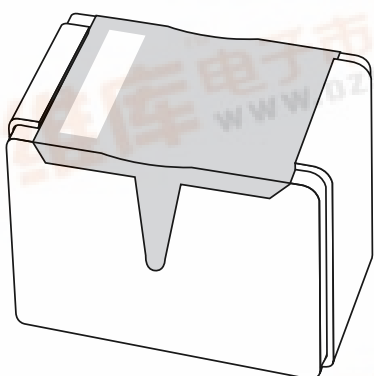


DISCRETE SEMICONDUCTORS

DATA SHEET



BZX284 series **Voltage regulator diodes**

Product specification
Supersedes data of 1996 Apr 17

1999 Apr 19

Voltage regulator diodes

BZX284 series

FEATURES

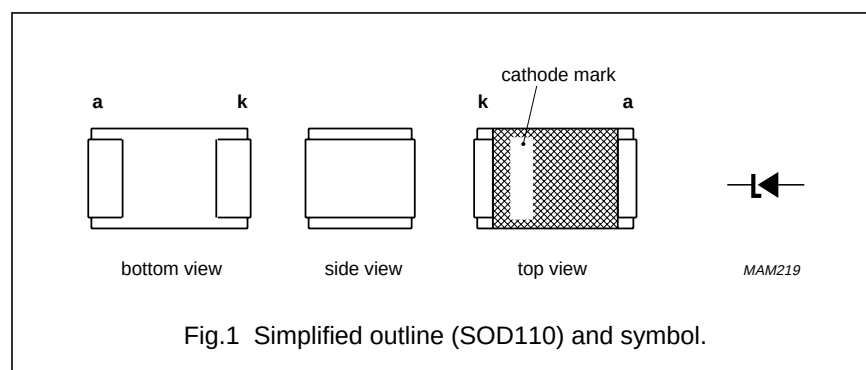
- Total power dissipation:
max. 400 mW
- Two tolerance series:
 $\pm 2\%$ and $\pm 5\%$
- Working voltage range:
nom. 2.4 to 75 V (E24 range).

APPLICATIONS

- General regulation functions.

DESCRIPTION

Low-power voltage regulator diodes in a small ceramic SMD SOD110 package. The diodes are available in the normalized E24 $\pm 2\%$ (BZX284-B) and $\pm 5\%$ (BZX284-C) tolerance range. The series consists of 37 types with nominal working voltages from 2.4 to 75 V.



MARKING

TYPE NUMBER	MARKING CODE	TYPE NUMBER	MARKING CODE	TYPE NUMBER	MARKING CODE	TYPE NUMBER	MARKING CODE
BZX284-B2V4	WO	BZX284-B15	XH	BZX284-C2V4	YO	BZX284-C15	ZH
BZX284-B2V7	WP	BZX284-B16	XI	BZX284-C2V7	YP	BZX284-C16	ZI
BZX284-B3V0	WQ	BZX284-B18	XJ	BZX284-C3V0	YQ	BZX284-C18	ZJ
BZX284-B3V3	WR	BZX284-B20	XK	BZX284-C3V3	YR	BZX284-C20	ZK
BZX284-B3V6	WS	BZX284-B22	XL	BZX284-C3V6	YS	BZX284-C22	ZL
BZX284-B3V9	WT	BZX284-B24	XM	BZX284-C3V9	YT	BZX284-C24	ZM
BZX284-B4V3	WU	BZX284-B27	XN	BZX284-C4V3	YU	BZX284-C27	ZN
BZX284-B4V7	WV	BZX284-B30	XO	BZX284-C4V7	YV	BZX284-C30	ZO
BZX284-B5V1	WW	BZX284-B33	XP	BZX284-C5V1	YW	BZX284-C33	ZP
BZX284-B5V6	WX	BZX284-B36	XQ	BZX284-C5V6	YX	BZX284-C36	ZQ
BZX284-B6V2	WY	BZX284-B39	XR	BZX284-C6V2	YY	BZX284-C39	ZR
BZX284-B6V8	WZ	BZX284-B43	XS	BZX284-C6V8	YZ	BZX284-C43	ZS
BZX284-B7V5	XA	BZX284-B47	XT	BZX284-C7V5	ZA	BZX284-C47	ZT
BZX284-B8V2	XB	BZX284-B51	XU	BZX284-C8V2	ZB	BZX284-C51	ZU
BZX284-B9V1	XC	BZX284-B56	XV	BZX284-C9V1	ZC	BZX284-C56	ZV
BZX284-B10	XD	BZX284-B62	XW	BZX284-C10	ZD	BZX284-C62	ZW
BZX284-B11	XE	BZX284-B68	XX	BZX284-C11	ZE	BZX284-C68	ZX
BZX284-B12	XF	BZX284-B75	XY	BZX284-C12	ZF	BZX284-C75	ZY
BZX284-B13	XG	—	—	BZX284-C13	ZG	—	—

Voltage regulator diodes

BZX284 series

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
I_F	continuous forward current		–	250	mA
I_{ZSM}	non-repetitive peak reverse current	$t_p = 100 \mu s$; square wave; $T_{amb} = 25^\circ C$ prior to surge	see Tables 1 and 2		
P_{tot}	total power dissipation	$T_{amb} = 25^\circ C$; note 1	–	400	mW
T_{stg}	storage temperature		–65	+150	$^\circ C$
T_j	junction temperature		–	150	$^\circ C$

Note

1. Device mounted on a printed-circuit board: $11 \times 25 \times 1.6$ mm.

ELECTRICAL CHARACTERISTICS

Total BZX284-B and C series

$T_j = 25^\circ C$ unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MAX.	UNIT
V_F	forward voltage	$I_F = 10$ mA; see Fig.4	0.9	V
		$I_F = 100$ mA; see Fig.4	1.1	V
I_R	reverse current			
	BZX284-B/C2V4	$V_R = 1$ V	50	μA
	BZX284-B/C2V7	$V_R = 1$ V	20	μA
	BZX284-B/C3V0	$V_R = 1$ V	10	μA
	BZX284-B/C3V3	$V_R = 1$ V	5	μA
	BZX284-B/C3V6	$V_R = 1$ V	5	μA
	BZX284-B/C3V9	$V_R = 1$ V	3	μA
	BZX284-B/C4V3	$V_R = 1$ V	3	μA
	BZX284-B/C4V7	$V_R = 2$ V	3	μA
	BZX284-B/C5V1	$V_R = 2$ V	2	μA
	BZX284-B/C5V6	$V_R = 2$ V	1	μA
	BZX284-B/C6V2	$V_R = 4$ V	3	μA
	BZX284-B/C6V8	$V_R = 4$ V	2	μA
	BZX284-B/C7V5	$V_R = 5$ V	1	μA
	BZX284-B/C8V2	$V_R = 5$ V	700	nA
	BZX284-B/C9V1	$V_R = 6$ V	500	nA
	BZX284-B/C10	$V_R = 7$ V	200	nA
	BZX284-B/C11	$V_R = 8$ V	100	nA
	BZX284-B/C12	$V_R = 8$ V	100	nA
	BZX284-B/C13	$V_R = 8$ V	100	nA
	BZX284-B/C15 to 75	$V_R = 0.7V_{Znom}$	50	nA

Voltage regulator diodes

BZX284 series

Table 1 Per type BZX284-B/C2V4 to B/C24
 $T_J = 25\text{ }^{\circ}\text{C}$ unless otherwise specified.

BZX284- B or C XXX	WORKING VOLTAGE V _Z (V) at I _{Ztest} = 5 mA				DIFFERENTIAL RESISTANCE r _{diff} (Ω)				TEMP. COEFF. S _Z (mV/K) at I _{Ztest} = 5 mA (see Figs 5 and 6)	DIODE CAP. C _d (pF) at f = 1 MHz; V _R = 0 V	NON-REPETITIVE PEAK REVERSE CURRENT I _{ZSM} (A) at t _p = 100 μs; T _{amb} = 25 °C
	Tot. ±2% (B)		Tot. ±5% (C)		at I _{Ztest} = 1 mA		at I _{Ztest} = 5 mA				
	MIN.	MAX.	MIN.	MAX.	TYP.	MAX.	TYP.	MAX.			
2V4	2.35	2.45	2.2	2.6	275	400	70	100	MAX.	MAX.	12.0
2V7	2.65	2.75	2.5	2.9	300	450	75	100			12.0
3V0	2.94	3.06	2.8	3.2	325	500	80	95			12.0
3V3	3.23	3.37	3.1	3.5	350	500	85	95			12.0
3V6	3.53	3.67	3.4	3.8	375	500	85	90			12.0
3V9	3.82	3.98	3.7	4.1	400	500	85	90			12.0
4V3	4.21	4.39	4.0	4.6	410	600	80	90			12.0
4V7	4.61	4.79	4.4	5.0	425	500	50	80			12.0
5V1	5.00	5.20	4.8	5.4	400	480	40	60			12.0
5V6	5.49	5.71	5.2	6.0	80	400	15	40			12.0
6V2	6.08	6.32	5.8	6.6	40	150	6	10			12.0
6V8	6.66	6.94	6.4	7.2	30	80	6	15			12.0
7V5	7.35	7.65	7.0	7.9	15	80	2	10			4.0
8V2	8.04	8.36	7.7	8.7	20	80	2	10			4.0
9V1	8.92	9.28	8.5	9.6	20	100	2	10			3.0
10	9.80	10.20	9.4	10.6	20	150	2	10			3.0
11	10.80	11.20	10.4	11.6	25	150	2	10			2.5
12	11.80	12.20	11.4	12.7	25	150	2	10			2.5
13	12.70	13.30	12.4	14.1	25	170	2	10			2.5
15	14.70	15.30	13.8	15.6	25	200	3	15			2.0
16	15.70	16.30	15.3	17.1	25	200	4	20			1.5
18	17.60	18.40	16.8	19.1	25	225	4	20			1.5
20	19.60	20.40	18.8	21.2	30	225	4	20			1.5
22	21.60	22.40	20.8	23.3	30	250	5	25			1.25
24	23.50	24.50	22.8	25.6	30	250	6	30			1.25

Voltage regulator diodes

BZX284 series

Table 2 Per type BZX284-B/C27 to B/C75 $T_j = 25\text{ }^{\circ}\text{C}$ unless otherwise specified.

BZX284-B or C XXX	WORKING VOLTAGE V _Z (V) at I _{Ztest} = 2 mA				DIFFERENTIAL RESISTANCE r _{diff} (Ω)				TEMP. COEFF. S _Z (mV/K) at I _{Ztest} = 2 mA	DIODE CAP. C _d (pF) at f = 1 MHz; V _R = 0 V	NON-REPETITIVE PEAK REVERSE CURRENT I _{ZSM} (A) at t _p = 100 μs; T _{amb} = 25 °C
	Tol. ±2% (B)		Tol. ±5% (C)		at I _{Ztest} = 0.5 mA		at I _{Ztest} = 2 mA				
	MIN.	MAX.	MIN.	MAX.	TYP.	MAX.	TYP.	MAX.			
27	26.50	27.50	25.1	28.9	35	250	8	40	MAX.	MAX.	1.0
30	29.40	30.60	28.0	32.0	35	250	10	40	66	1.0	
33	32.30	33.70	31.0	35.0	40	275	11	40	60	0.9	
36	35.30	36.70	34.0	38.0	40	300	15	60	59	0.8	
39	38.20	39.80	37.0	41.0	40	300	25	75	58	0.7	
43	42.10	43.90	40.0	46.0	45	325	30	80	56	0.6	
47	46.10	47.90	44.0	50.0	45	325	30	90	55	0.5	
51	50.00	52.00	48.0	54.0	45	350	35	110	52	0.4	
56	54.90	57.10	52.0	60.0	50	375	40	120	49	0.3	
62	60.80	63.20	58.0	66.0	60	400	50	140	44	0.3	
68	66.60	69.40	64.0	72.0	75	400	55	160	40	0.25	
75	73.50	76.50	70.0	79.0	85	400	70	175	35	0.2	

Voltage regulator diodes

BZX284 series

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th j-a}	thermal resistance from junction to ambient	note 1	315	K/W

Note

1. Device mounted on a printed-circuit board: 11 × 25 × 1.6 mm.

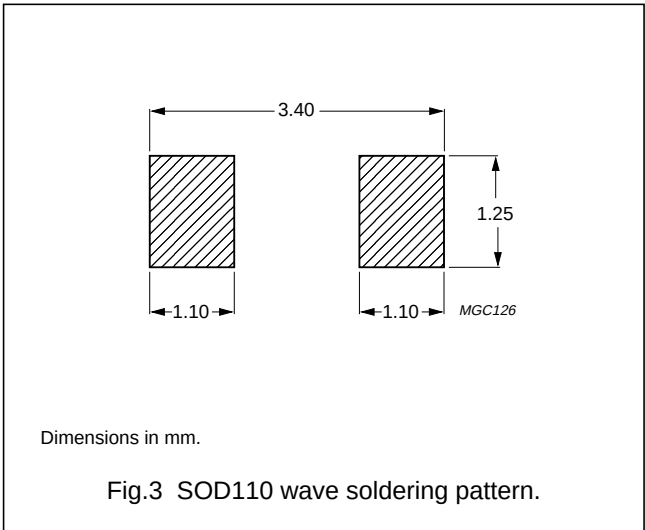
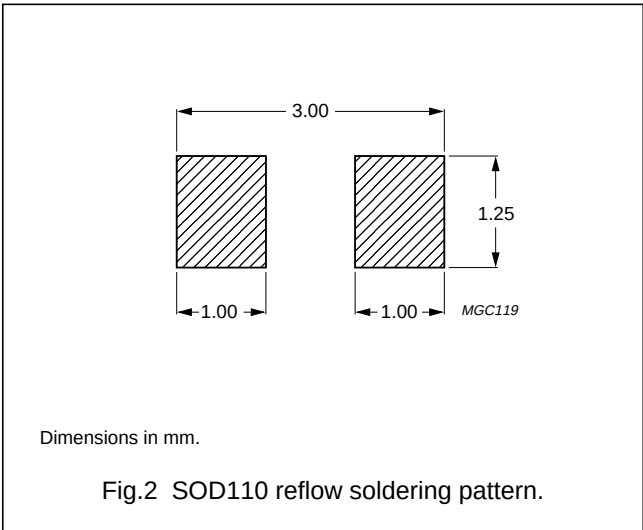
MOUNTING

Reflow soldering

Follow standard reflow soldering techniques to ensure correct application of solder paste and placement of the SOD110 package (see Fig.2).

Wave soldering

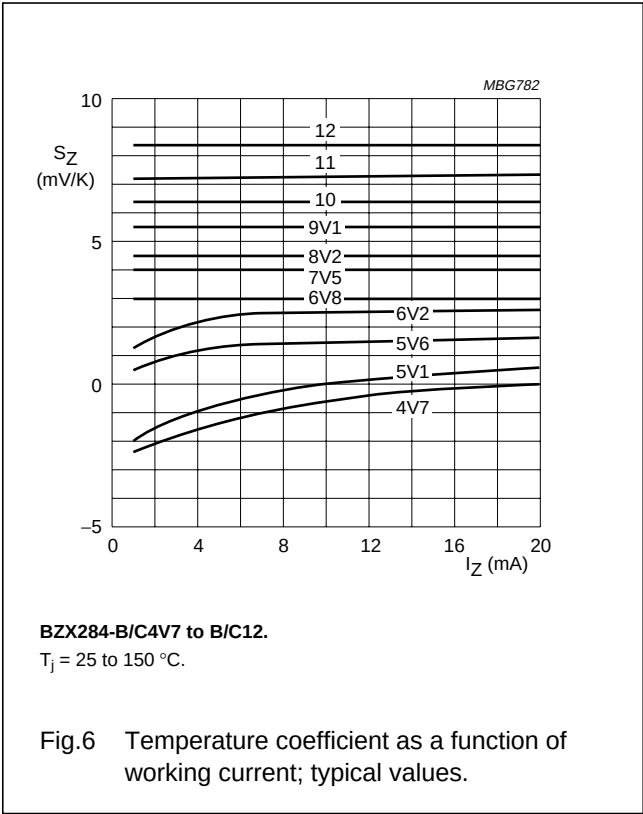
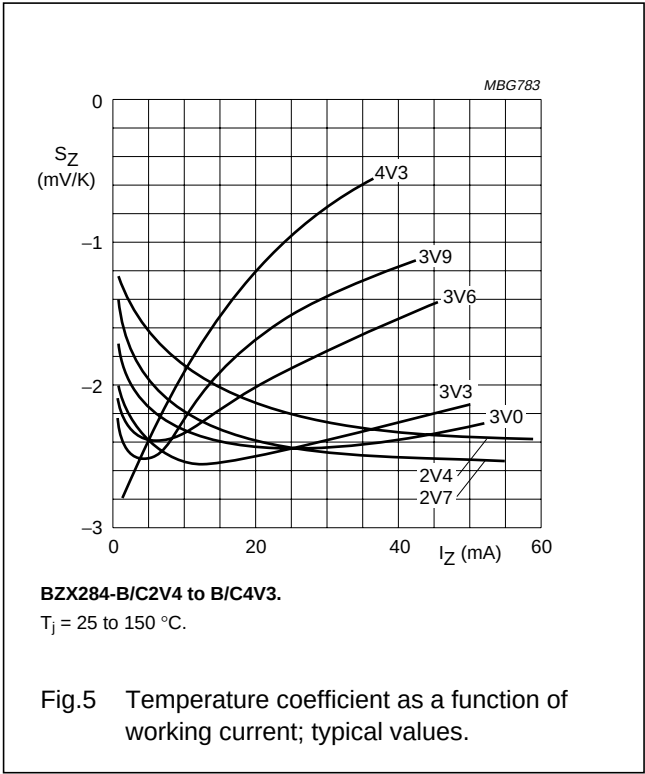
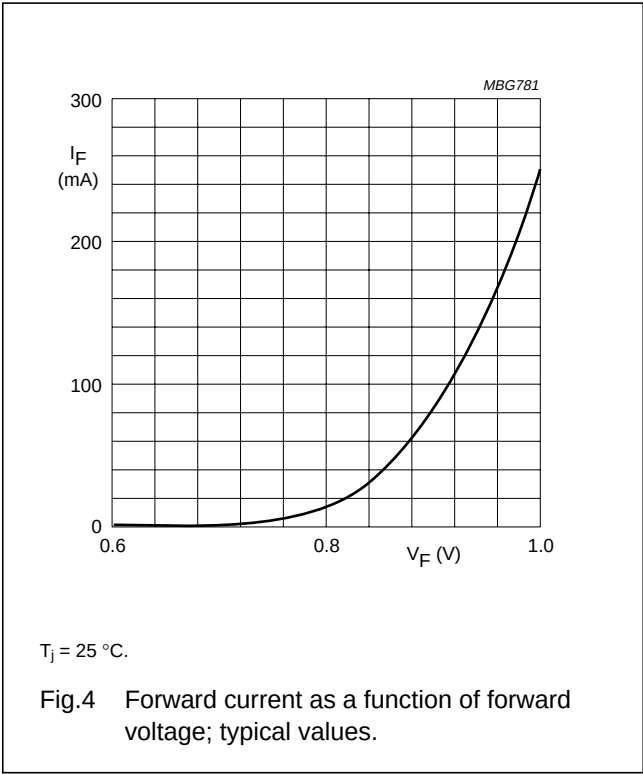
Before wave soldering, attach SOD110 packages to the printed-circuit boards using a small dot of thermo-setting epoxy or UV-curing adhesive centred between the soldering lands (see Fig.3).



Voltage regulator diodes

BZX284 series

GRAPHICAL DATA



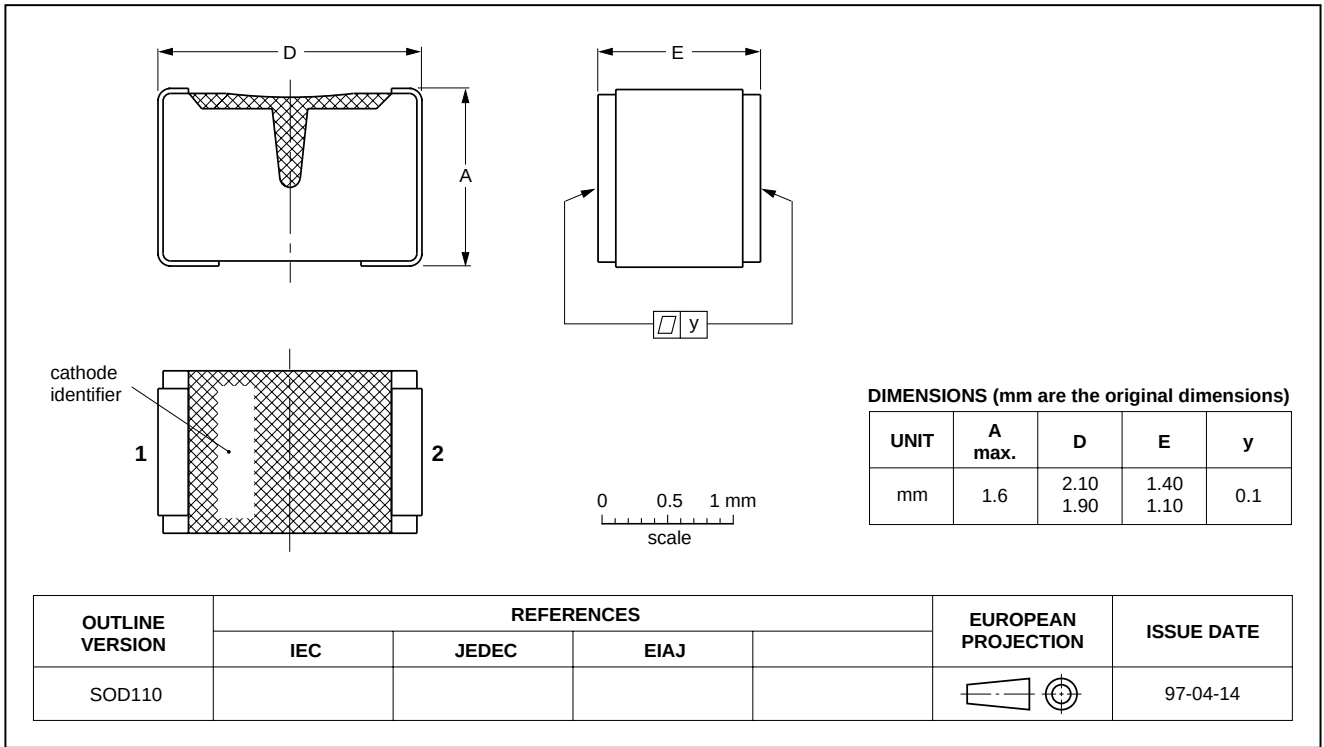
Voltage regulator diodes

BZX284 series

PACKAGE OUTLINE

Very small ceramic rectangular surface mounted package

SOD110



DEFINITIONS

Data sheet status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	
Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
Application information	
Where application information is given, it is advisory and does not form part of the specification.	

LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.

Voltage regulator diodes

BZX284 series

NOTES

Voltage regulator diodes

BZX284 series

NOTES

Voltage regulator diodes

BZX284 series

NOTES

Philips Semiconductors – a worldwide company

Argentina: see South America

Australia: 34 Waterloo Road, NORTH RYDE, NSW 2113,
Tel. +61 2 9805 4455, Fax. +61 2 9805 4466

Austria: Computerstr. 6, A-1101 WIEN, P.O. Box 213,
Tel. +43 1 60 101 1248, Fax. +43 1 60 101 1210

Belarus: Hotel Minsk Business Center, Bld. 3, r. 1211, Volodarski Str. 6,
220050 MINSK, Tel. +375 172 20 0733, Fax. +375 172 20 0773

Belgium: see The Netherlands

Brazil: see South America

Bulgaria: Philips Bulgaria Ltd., Energoproject, 15th floor,
51 James Bourchier Blvd., 1407 SOFIA,
Tel. +359 2 68 9211, Fax. +359 2 68 9102

Canada: PHILIPS SEMICONDUCTORS/COMPONENTS,
Tel. +1 800 234 7381, Fax. +1 800 943 0087

China/Hong Kong: 501 Hong Kong Industrial Technology Centre,
72 Tat Chee Avenue, Kowloon Tong, HONG KONG,
Tel. +852 2319 7888, Fax. +852 2319 7700

Colombia: see South America

Czech Republic: see Austria

Denmark: Sydhavnsgade 23, 1780 COPENHAGEN V,
Tel. +45 33 29 3333, Fax. +45 33 29 3905

Finland: Sinikalliontie 3, FIN-02630 ESPOO,
Tel. +358 9 615 800, Fax. +358 9 6158 0920

France: 51 Rue Carnot, BP317, 92156 SURESNES Cedex,
Tel. +33 1 4099 6161, Fax. +33 1 4099 6427

Germany: Hammerbrookstraße 69, D-20097 HAMBURG,
Tel. +49 40 2353 60, Fax. +49 40 2353 6300

Hungary: see Austria

India: Philips INDIA Ltd, Band Box Building, 2nd floor,
254-D, Dr. Annie Besant Road, Worli, MUMBAI 400 025,
Tel. +91 22 493 8541, Fax. +91 22 493 0966

Indonesia: PT Philips Development Corporation, Semiconductors Division,
Gedung Philips, Jl. Buncit Raya Kav.99-100, JAKARTA 12510,
Tel. +62 21 794 0040 ext. 2501, Fax. +62 21 794 0080

Ireland: Newstead, Clonskeagh, DUBLIN 14,
Tel. +353 1 7640 000, Fax. +353 1 7640 200

Israel: RAPAC Electronics, 7 Kehilat Saloniki St, PO Box 18053,
TEL AVIV 61180, Tel. +972 3 645 0444, Fax. +972 3 649 1007

Italy: PHILIPS SEMICONDUCTORS, Piazza IV Novembre 3,
20124 MILANO, Tel. +39 2 6752 2531, Fax. +39 2 6752 2557

Japan: Philips Bldg 13-37, Kohnan 2-chome, Minato-ku,
TOKYO 108-8507, Tel. +81 3 3740 5130, Fax. +81 3 3740 5077

Korea: Philips House, 260-199 Itaewon-dong, Yongsan-ku, SEOUL,
Tel. +82 2 709 1412, Fax. +82 2 709 1415

Malaysia: No. 76 Jalan Universiti, 46200 PETALING JAYA, SELANGOR,
Tel. +60 3 750 5214, Fax. +60 3 757 4880

Mexico: 5900 Gateway East, Suite 200, EL PASO, TEXAS 79905,
Tel. +9-5 800 234 7381, Fax +9-5 800 943 0087

Middle East: see Italy

Netherlands: Postbus 90050, 5600 PB EINDHOVEN, Bldg. VB,
Tel. +31 40 27 82785, Fax. +31 40 27 88399

New Zealand: 2 Wagener Place, C.P.O. Box 1041, AUCKLAND,
Tel. +64 9 849 4160, Fax. +64 9 849 7811

Norway: Box 1, Manglerud 0612, OSLO,
Tel. +47 22 74 8000, Fax. +47 22 74 8341

Pakistan: see Singapore

Philippines: Philips Semiconductors Philippines Inc.,
106 Valero St. Salcedo Village, P.O. Box 2108 MCC, MAKATI,
Metro MANILA, Tel. +63 2 816 6380, Fax. +63 2 817 3474

Poland: Ul. Lukiska 10, PL 04-123 WARSZAWA,
Tel. +48 22 612 2831, Fax. +48 22 612 2327

Portugal: see Spain

Romania: see Italy

Russia: Philips Russia, Ul. Usatcheva 35A, 119048 MOSCOW,
Tel. +7 095 755 6918, Fax. +7 095 755 6919

Singapore: Lorong 1, Toa Payoh, SINGAPORE 319762,
Tel. +65 350 2538, Fax. +65 251 6500

Slovakia: see Austria

Slovenia: see Italy

South Africa: S.A. PHILIPS Pty Ltd., 195-215 Main Road Martindale,
2092 JOHANNESBURG, P.O. Box 7430 Johannesburg 2000,
Tel. +27 11 470 5911, Fax. +27 11 470 5494

South America: Al. Vicente Pinzon, 173, 6th floor,
04547-130 SÃO PAULO, SP, Brazil,
Tel. +55 11 821 2333, Fax. +55 11 821 2382

Spain: Balmes 22, 08007 BARCELONA,
Tel. +34 93 301 6312, Fax. +34 93 301 4107

Sweden: Kottbygatan 7, Akalla, S-16485 STOCKHOLM,
Tel. +46 8 5985 2000, Fax. +46 8 5985 2745

Switzerland: Allmendstrasse 140, CH-8027 ZÜRICH,
Tel. +41 1 488 2741 Fax. +41 1 488 3263

Taiwan: Philips Semiconductors, 6F, No. 96, Chien Kuo N. Rd., Sec. 1,
TAIPEI, Taiwan Tel. +886 2 2134 2886, Fax. +886 2 2134 2874

Thailand: PHILIPS ELECTRONICS (THAILAND) Ltd.,
209/2 Sanpavuth-Bangna Road Prakanong, BANGKOK 10260,
Tel. +66 2 745 4090, Fax. +66 2 398 0793

Turkey: Talatpasa Cad. No. 5, 80640 GÜLTEPE/ISTANBUL,
Tel. +90 212 279 2770, Fax. +90 212 282 6707

Ukraine: PHILIPS UKRAINE, 4 Patrice Lumumba str., Building B, Floor 7,
252042 KIEV, Tel. +380 44 264 2776, Fax. +380 44 268 0461

United Kingdom: Philips Semiconductors Ltd., 276 Bath Road, Hayes,
MIDDLESEX UB3 5BX, Tel. +44 181 730 5000, Fax. +44 181 754 8421

United States: 811 East Arques Avenue, SUNNYVALE, CA 94088-3409,
Tel. +1 800 234 7381, Fax. +1 800 943 0087

Uruguay: see South America

Vietnam: see Singapore

Yugoslavia: PHILIPS, Trg N. Pasica 5/v, 11000 BEOGRAD,
Tel. +381 11 62 5344, Fax. +381 11 63 5777

For all other countries apply to: Philips Semiconductors,
International Marketing & Sales Communications, Building BE-p, P.O. Box 218,
5600 MD EINDHOVEN, The Netherlands, Fax. +31 40 27 24825

Internet: <http://www.semiconductors.philips.com>

© Philips Electronics N.V. 1999

SCA63

All rights are reserved. Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner.

The information presented in this document does not form part of any quotation or contract, is believed to be accurate and reliable and may be changed without notice. No liability will be accepted by the publisher for any consequence of its use. Publication thereof does not convey nor imply any license under patent- or other industrial or intellectual property rights.

Printed in The Netherlands

115002/3180/03/pp12

Date of release: 1999 Apr 19

Document order number: 9397 750 05488

Let's make things better.